

| V _{DSS} | 30V |
|----------------------------|-------|
| R _{DS(on)} (Max.) | 240mΩ |
| Ι _D | ±1.4A |
| P _D | 1.0W |

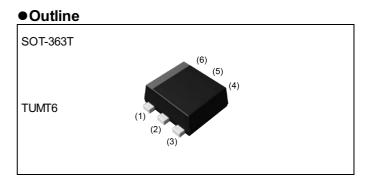
Features

- 1) Low on resistance.
- 2) -4V Drive.

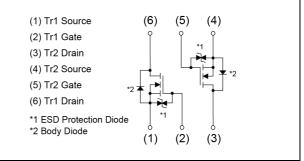
Application

Switching

- 3) Built-in G-S Protection Diode.
- 4) Small Surface Mount Package (TUMT6).
- 5) Pb-free lead plating ; RoHS compliant



Inner circuit



Packaging specifications

| | Packing | Embossed Tape |
|------|---------------------------|------------------|
| Туре | Reel size (mm) | 180 |
| | Tape width (mm) | 8 |
| 51 | Basic ordering unit (pcs) | 3000 |
| | Taping code | TR |
| | Marking | K02 |

• Absolute maximum ratings ($T_a = 25^{\circ}C$,unless otherwise specified) <Tr1 and Tr2>

| U () | , | • • | | |
|------------------------------------|--------------------|---------------------|------|----|
| Parameter | Symbol | Value | Unit | |
| Drain - Source voltage | V _{DSS} | 30 | V | |
| Continuous drain current | Ι _D | ±1.4 | А | |
| Pulsed drain current | ا _{DP} *1 | ±5.6 | А | |
| Gate - Source voltage | | V _{GSS} | 20 | V |
| | total | - P _D *2 | 1.0 | W |
| Power dissipation | element | | 0.7 | |
| | total | P _D *3 | 0.91 | |
| Junction temperature | | Tj | 150 | °C |
| Operating junction and storage ter | T _{stg} | -55 to +150 | °C | |

•Thermal resistance

| Parameter | | Symbol | Values | | | Linit |
|--|---------|-----------------|--------|------|------|-------|
| | | Symbol | Min. | Тур. | Max. | Unit |
| Thermal resistance, junction - ambient | total | D *2 | - | - | 125 | |
| | element | R_{thJA}^{*2} | - | - | 179 | °C/W |
| | total | R_{thJA}^{*3} | - | - | 137 | |

• Electrical characteristics ($T_a = 25^{\circ}C$) <Tr1 and Tr2>

| Devenueter | Currente e l | Conditions | Values | | | 1.1 | |
|--|------------------------|---|----------------|-----------|------|--------|--|
| Parameter | Symbol | Conditions | Min. Typ. Max. | | Unit | | |
| Drain - Source breakdown voltage | V _{(BR)DSS} | V _{GS} = 0V, I _D = 1mA | 30 | - | - | V | |
| Breakdown voltage | ΔV _{(BR)DSS} | I _D = 1mA | | 29.0 | | mV/°C | |
| temperature coefficient | ΔT_j | referenced to 25°C | - | 29.0 | - | mv/ C | |
| Zero gate voltage drain current | I _{DSS} | V _{DS} = 30V, V _{GS} = 0V | - | - | 1 | μA | |
| Gate - Source leakage current | I _{GSS} | V _{DS} = 0V, V _{GS} = 20V | - | - | 10 | μA | |
| Gate threshold voltage | V _{GS(th)} | V _{DS} = 10V, I _D = 1mA | 1.0 | - | 2.5 | V | |
| Gate threshold voltage | $\Delta V_{GS(th)}$ | I _D = 1mA | | -1.6 | | m\//°C | |
| temperature coefficient | ΔTj | referenced to 25°C | | | - | mV/°C | |
| | | V _{GS} = 10V, I _D = 1.4A | - | 170 | 240 | | |
| Static drain - source on - state resistance | R _{DS(on)} *4 | V _{GS} = 4.5V, I _D = 1.4A | - | 250 350 m | | mΩ | |
| | | V _{GS} = 4.0V, I _D = 1.4A | - | 270 | 380 | - | |
| Gate resistance | R _G | f = 1MHz, open drain | - | 20 | - | Ω | |
| Forward Transfer Admittance | Y _{fs} *4 | V _{DS} = 10V, I _D = 1.4A | | - | - | S | |



•Electrical characteristics ($T_a = 25^{\circ}C$) <Tr1 and Tr2>

| Deremeter | Cump of | Conditions | | Unit | | |
|------------------------------|------------------------|-------------------------------------|------|------|------|------|
| Parameter | Symbol | Conditions | Min. | Тур. | Max. | Unit |
| Input capacitance | C _{iss} | V _{GS} = 0V | - | 70 | - | |
| Output capacitance | C _{oss} | V _{DS} = 10V | - | 15 | - | pF |
| Reverse transfer capacitance | C _{rss} | f = 1MHz | - | 12 | - | |
| Turn - on delay time | t _{d(on)} *4 | $V_{DD} \simeq 15 V, V_{GS} = 10 V$ | - | 6 | - | |
| Rise time | t _r *4 | I _D = 0.7A | - | 6 | - | 20 |
| Turn - off delay time | t _{d(off)} *4 | R _L = 21Ω | - | 13 | - | ns |
| Fall time | t _f *4 | R _G = 10Ω | - | 8 | - | |

•Gate charge characteristics ($T_a = 25^{\circ}C$) <Tr1 and Tr2>

| Parameter | Symbol Conditions | | | Unit | | | |
|----------------------|--------------------|-----------------------|------|------|------|-------|--|
| | Symbol | Conditions | Min. | Тур. | Max. | Offic | |
| Total gate charge | Q_g^{*4} | $V_{DD} \simeq 15V$ | - | 1.4 | 2.0 | | |
| Gate - Source charge | Q _{gs} *4 | I _D = 1.4A | - | 0.6 | - | nC | |
| Gate - Drain charge | Q _{gd} *4 | V _{GS} = 5V | - | 0.3 | - | | |

•Body diode electrical characteristics (Source-Drain) (T_a = 25°C)

<Tr1 and Tr2>

| Parameter | Symbol | Conditions | Values | | | Unit |
|----------------------------|----------------|---|--------|------|------|------|
| | Symbol | Conditions | Min. | Тур. | Max. | Unit |
| Continuous forward current | ۱ _s | $T = 25^{\circ}$ | - | - | 0.6 | ^ |
| Pulse forward current | I_{SP}^{*1} | T _a = 25°C | - | - | 5.6 | A |
| Forward voltage | V_{SD}^{*4} | V _{GS} = 0V, I _S = 0.6A | - | - | 1.2 | V |

*1 Pw \leq 10µs , Duty cycle \leq 1%

- *2 Mounted on a ceramic board (30×30×0.8mm)
- *3 Mounted on a FR4 (25×25×0.8mm,Cu pad:625mm²)
- *4 Pulsed



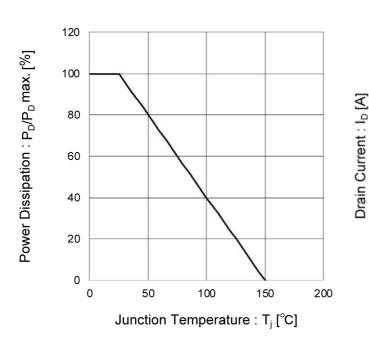
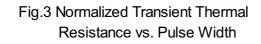
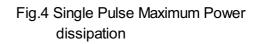


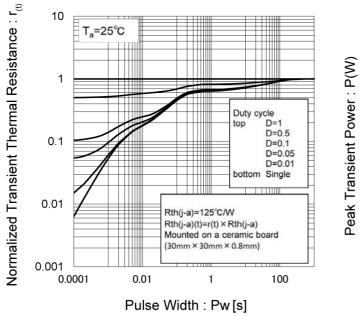
Fig.1 Power Dissipation Derating Curve

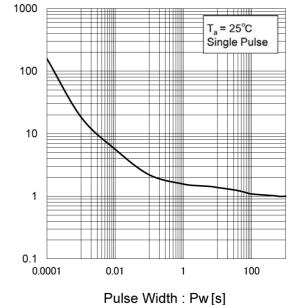
Operation in this area is limited by R_{DS}(on) 10 $(V_{GS} = 10V)$ P_W = 100µs 1 $P_W = 1ms$ $P_w = 10ms$ DC Operation 0.1 T_a=25°C Single Pulse Mounted on a ceramic board (30mm × 30mm × 0.8mm) 0.01 10 100 0.1 1 Drain - Source Voltage : V_{DS} [V]

Fig.2 Maximum Safe Operating Area











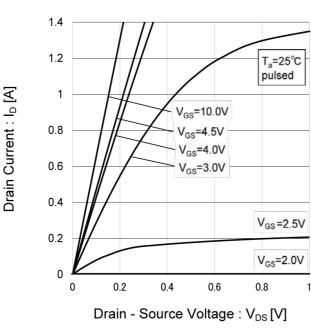


Fig.5 Typical Output Characteristics(I)

Fig.6 Typical Output Characteristics(II)

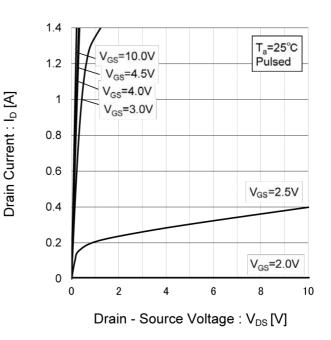


Fig.7 Breakdown Voltage vs. Junction Temperature

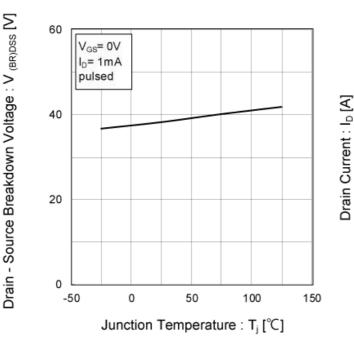
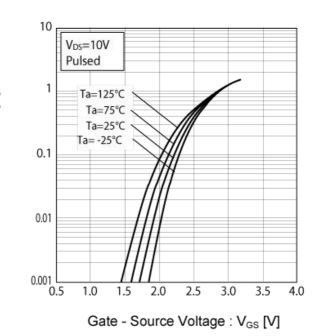


Fig.8 Typical Transfer Characteristics





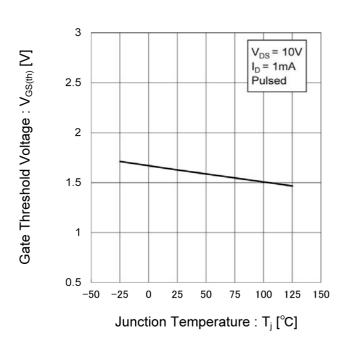


Fig.9 Gate Threshold Voltage vs.

Junction Temperature

Fig.10 Forward Transfer Admittance vs. Drain Current

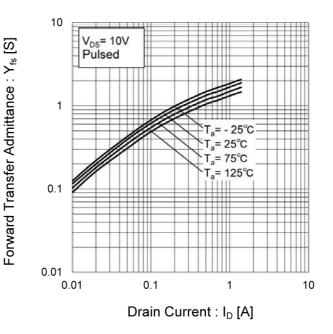
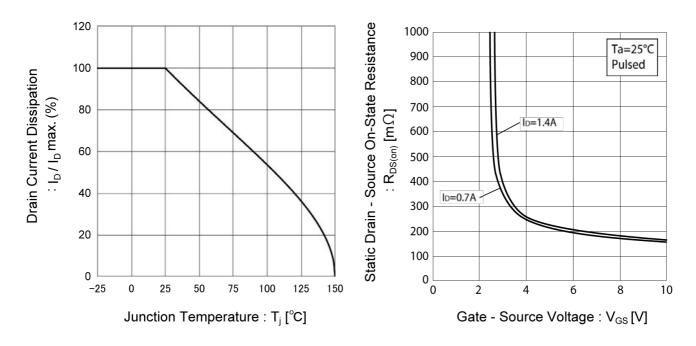


Fig.11 Drain Current Derating Curve

Fig.12 Static Drain - Source On - State Resistance vs. Gate Source Voltage





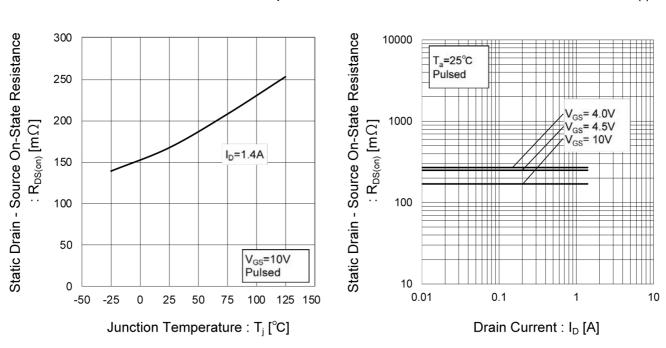
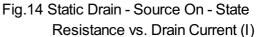


Fig.13 Static Drain - Source On - State Resistance vs. Junction Temperature







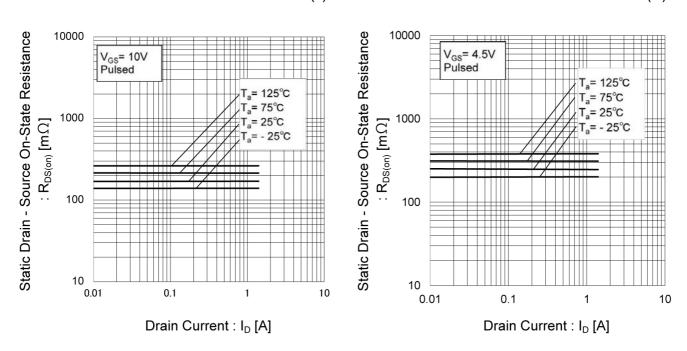
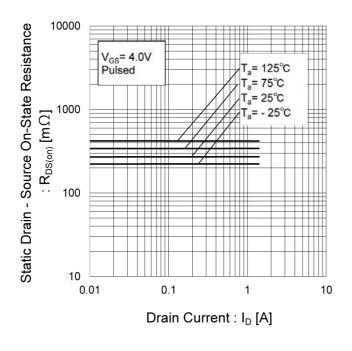


Fig.15 Static Drain - Source On - State Resistance vs. Drain Current (II) Fig.16 Static Drain - Source On - State Resistance vs. Drain Current (III)

Fig.17 Static Drain - Source On - State Resistance vs. Drain Current (IV)





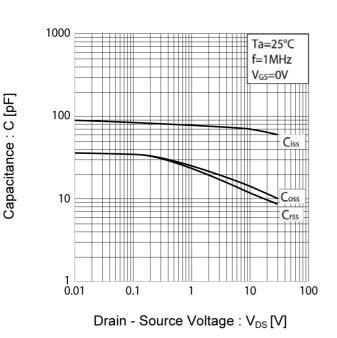
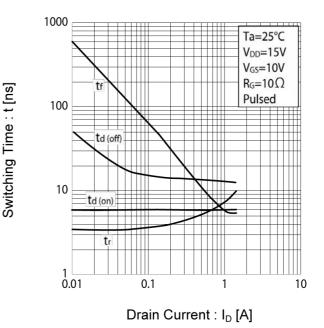
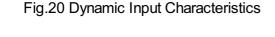


Fig.18 Typical Capacitance vs. Drain - Source Voltage

Fig.19 Switching Characteristics





Gate - Source Voltage : V_{GS} [V]

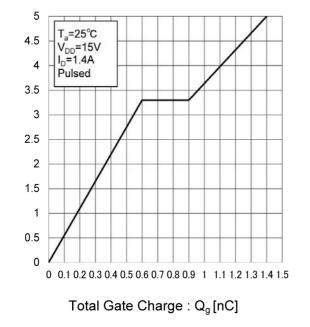
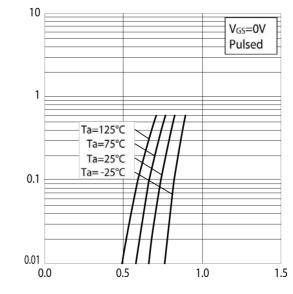


Fig.21 Source Current vs. Source Drain Voltage



Source-Drain Voltage : V_{SD} [V]



Source Current :I_s [A]

•Measurement circuits <It is the same for the Tr1 and Tr2>



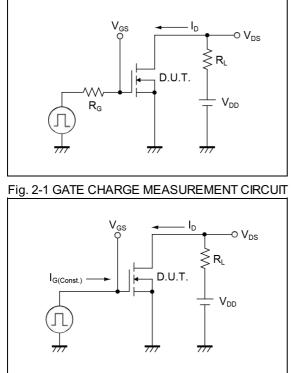


Fig. 1-2 SWITCHING WAVEFORMS

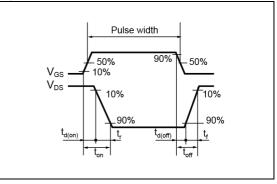
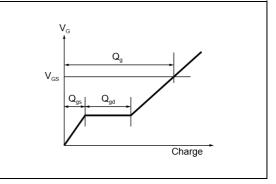


Fig. 2-2 GATE CHARGE WAVEFORM

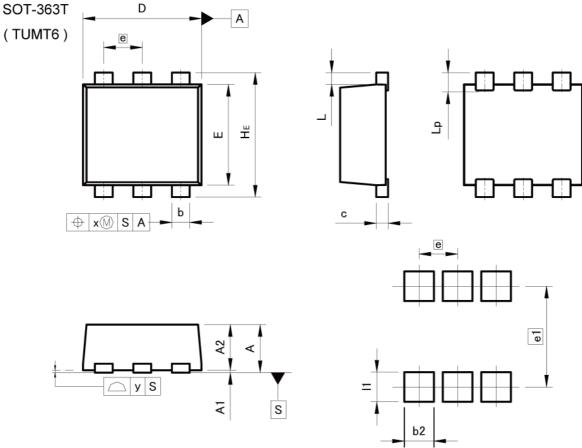


Notice

This product might cause chip aging and breakdown under the large electrified environment. Please consider to design ESD protection circuit.



Dimensions



Pattern of terminal position areas [Not a pattern of soldering pads]

| | MILIMETERS | | INC | HES |
|-----|--------------|-------|-------|-------|
| DIM | MIN | MAX | MIN | MAX |
| A | <u></u> | 0.85 | - | 0.033 |
| A1 | 0.00 | 0.05 | 0.000 | 0.002 |
| A2 | 0.72 | 0.82 | 0.028 | 0.032 |
| b | 0.25 | 0.40 | 0.010 | 0.016 |
| с | 0.12 | 0.22 | 0.005 | 0.009 |
| D | 1.90 | 2.10 | 0.075 | 0.083 |
| E | 1.60 | 1.80 | 0.063 | 0.071 |
| e | 0. | 65 | 0.026 |)26 |
| HE | 2.00 | 2.20 | 0.079 | 0.087 |
| L | 0. | 20 | 0.0 | 800 |
| Lp | <u>20</u> 03 | 0.40 | - | 0.016 |
| x | <u></u> | 0.10 | 1 | 0.004 |
| у | | 0.10 | - | 0.004 |
| | MILIM | ETERS | INC | HES |
| | MIN | MAX | MIN | MAX |
| b2 | - | 0.50 | - | 0.020 |
| e1 | 1. | 70 | 0.0 | 67 |
| 11 | <u>24</u> 3 | 0.50 | - | 0.020 |

Dimension in mm/inches



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| ſ | CLASSⅢ | CLASSⅢ | CLASS II b | CLASSI |
| | CLASSⅣ | CLASSIL | CLASSⅢ | CLASSI |

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 - [b] Use of our Products outdoors or in places where the Products are exposed to direct sunlight or dust
 - [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl₂, H₂S, NH₃, SO₂, and NO₂
 - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
 - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
 - [f] Sealing or coating our Products with resin or other coating materials
 - [g] Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
 - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse. is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

Precaution for Mounting / Circuit board design

- 1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
- 2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

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- 1. If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.
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This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

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 - [b] the temperature or humidity exceeds those recommended by ROHM
 - [c] the Products are exposed to direct sunshine or condensation
 - [d] the Products are exposed to high Electrostatic
- 2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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